



2.30" (60.20mm) Φ 5.00mm 8*8 Bi-Color Dot Matrix Displays

Features:

- *High dot intensity
- *Wide viewing angle
- *Bi- colors
- *Black face White dot
- *RoHS compliant

Available option:

- *Alternative face and dot color
- *Cropped terminal pins
- *Available emitting color
- *Low current version

Electro/Optical Characteristics If=20mA Ta=25°C

Part Number Row Cathode Column Anode	Part Number Row Anode Column Cathode	Emitting Color	Peak Wavelength	Forward Voltage V _F /Dot		Luminous Intensity I _v /Dot	
				Typ.	Max.	Min.	Typ.
NFM-23881ASG-11-S-L3.1	NFM-23881BSG-11-S-L3.1	GaAlAs/GaAs Hi-Red	660	1.80	2.20	8.0	12.0
		GaP/GaP Green	570	2.20	2.50	7.0	11.0
NFM-23881AUEUG-11-S-L3.1	NFM-23881BUEUG-11-S-L3.1	AlGaInP/GaAs Ultra Orange	632	2.00	2.50	40.0	60.0
		AlGaInP/GaAs Ultra Green	574	2.10	2.50	25.0	40.0
NFM-23881ADUG-11-S-L3.1	NFM-23881BDUG-11-S-L3.1	GaAlAs/GaAs Super-Red	660	1.80	2.20	22.0	28.0
		AlGaInP/GaAs Ultra Green	574	2.10	2.50	25.0	40.0
Units			nm	V		mcd	

Maximum Ratings Ta=25°C (Derate above 25°C)

Characteristic	Test Condition	Symbol	S	G	UE	UG	D	Units
Pulse Forward Current Per Dot	1/10duty cycle 0.1ms Pulse width	I _{FP}	100	100	100	100	100	mA
DC Forward Current Per Dot		I _F	25	30	30	30	25	mA
Reverse Current Per Dot	V _R =5V	I _R	10	10	10	10	10	μA
Power Dissipation		P _D	60*64	80*64	65*64	75*64	60*64	mW
Operating Temperature		T _{OPR}	-40 to +80					°C
Storage Temperature		T _{TSG}	-40 to +85					°C
Lead soldering temperature	1.60mm from body maximum 3 seconds		260					°C

Checked

Chen N.H.

Approved

Jason Chen

Date

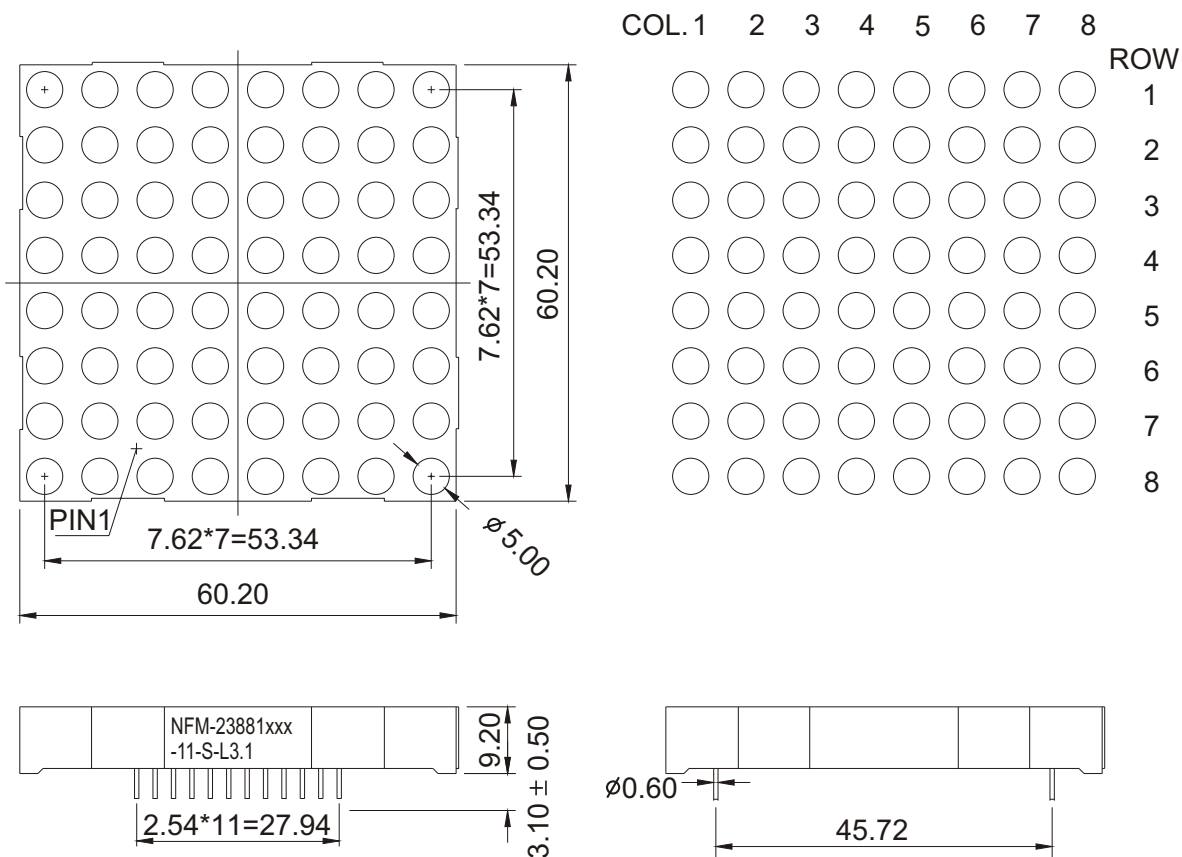
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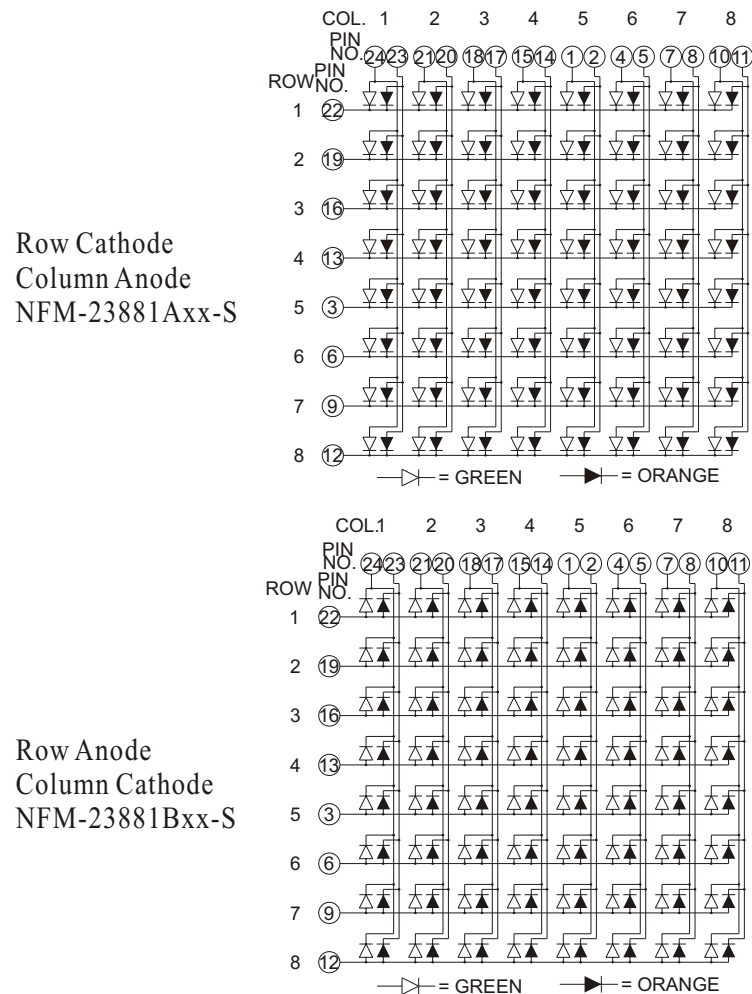


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PACKAGE DIMENSION



INTERNAL CIRCUIT DIAGRAM



Tolerance \pm 0.25mm unless stated

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